

Amorphous and liquid semiconductors - proceedings of the Seventh International Conference on Amorphous and Liquid Semiconductors, Edinburgh, June-27 July 1, 1977

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Soviet Union. Voenno-Morskoi Flot -- History -- World War, 1939-1945.

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Liquid semiconductors -- Congresses.

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Chakraborty, Simulation of Hysteresis in Bending of a SMA Beam under Cyclic Mechanical Load, 2nd ASCE India Conference on Challenges of Resilient and Sustainable Infrastructure Development in Emerging Economies, Novotel Kolkata Hotel and Residences, Kolkata, India, March 02 - 04, 2020 71 D. JOURNAL OF MATERIALS SCIENCE 29, 3837—3842 1994.

Method of doping a body of amorphous semiconductor material by ion implantation

Ganguly, Modelling and Analysis of a Solar Biomass Hybrid Vapour Absorption Refrigeration System for running a Cold Storage of Potato in India, PREPARE U - Preprint Archive, 1 1. Syam, Degradation of input displacement power factor by Input Current Filter and its compensation for a Matrix Converter, 1-6, IEEE International Conference on Power Electronics, Drives and Energy Systems 2018, Chennai, India, 2018 544 Arindam Sinharoy, Pranab Roy, Hafizur Rahaman, Computing Fréchet Distance Metric based L-Shape Tile Decomposition for E-Beam Lithography, 313-318, Computing Fréchet Distance Metric based L-Shape Tile Decomposition for E-Beam Lithography, 2018 545 Rastogi V. Roy Chowdhury, Prediction of Elastic Constants of Spiral MWCNT Reinforced Nanocomposites by Finite Element Analysis, International

Conference

The optical constants refractive index n and absorption index k of Se 75Ge 7Sb 18 thin films were determined in the spectral range of 0. Bhattacharjya, Robust design optimization of underground concrete tunnel subjected to seismic excitation, 64th Congress of ISTAM 2019, IIT, Bhubaneswar, Dec 9- 12, 2009, 2019 225 Dey N. It was, therefore, believed that ion implantation methods to dope amorphous semiconductor materials is not a technically suitable process.

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